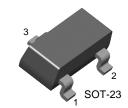


## KST10

### **VHF/UHF Transistor**



1. Base 2. Emitter 3. Collector

## **NPN Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector Base Voltage	30	V
$V_{CEO}$	Collector-Emitter Voltage	25	V
$V_{EBO}$	Emitter-Base Voltage	3	V
P <sub>C</sub>	Collector Power Dissipation	350	mW
T <sub>STG</sub>	Storage Temperature	150	°C
R <sub>TH</sub> (j-a)	Thermal Resistance junction to Ambient	357	°C/W

Refer to KSP10 for graphs

### **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

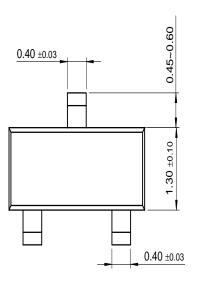
Symbol	Parameter	Test Condition	Min.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =100μA, I <sub>E</sub> =0	30		V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =1mA, I <sub>B</sub> =0	25		V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =10μA, I <sub>C</sub> =0	3		V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB}=25V$ , $I_{E}=0$		100	nA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{BE}=2V, I_{C}=0$		100	nA
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> =10V, I <sub>C</sub> =4mA	60		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =4mA, I <sub>B</sub> =0.4mA		0.5	V
V <sub>BE</sub>	Base-Emitter On Voltage	V <sub>CE</sub> =10V, I <sub>C</sub> =4mA		0.95	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =10V, I <sub>C</sub> =4mA, f=100MHz	650		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz		0.7	pF
C <sub>rb</sub>	Common-Base Feedback Capacitance	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz		0.65	pF
C <sub>c·rbb</sub> ′	Collector Base Time Constant	V <sub>CB</sub> =10V, I <sub>C</sub> =4mA, f=31.8MHz		9	pF

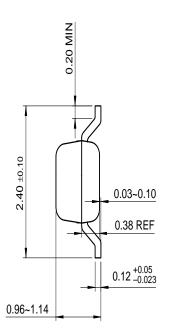


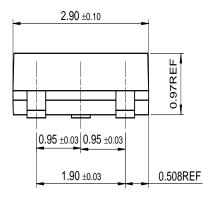
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# **Package Dimensions**

## **SOT-23**







Dimensions in Millimeters

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EnSigna™	$I^2C^{TM}$	$OCX^{TM}$	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
The Power Franchise™		OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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